NSN 5961-01-150-1268

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-150-1268 **Inclosure Material:** Glass **Overall Length:** 0.165 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.110 inches **End Application:** Missile, minuteman lgm-30 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Hardness critical item **Nuclear Hardness Critical Feature:** Hardened **Test Data Document:** 81205-10-22475 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Yes - demil/mli Fiig:

Demilitarization:

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